

PROCEEDINGS OF SPIE

Physics, Simulation, and Photonic Engineering of Photovoltaic Devices VIII

**Alexandre Freundlich
Laurent Lombez
Masakazu Sugiyama**
Editors

**5–7 February 2019
San Francisco, California, United States**

Sponsored and Published by
SPIE

Volume 10913

Proceedings of SPIE 0277-786X, V. 10913

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Physics, Simulation, and Photonic Engineering of Photovoltaic Devices VIII, edited by Alexandre Freundlich,
Laurent Lombez, Masakazu Sugiyama, Proc. of SPIE Vol. 10913, 1091301 · © 2019 SPIE
CCC code: 0277-786X/19/\$18 · doi: 10.1117/12.2531058

Proc. of SPIE Vol. 10913 1091301-1

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Author(s), "Title of Paper," in *Physics, Simulation, and Photonic Engineering of Photovoltaic Devices VIII*, edited by Alexandre Freundlich, Laurent Lombez, Masakazu Sugiyama, Proceedings of SPIE Vol. 10913 (SPIE, Bellingham, WA, 2019) Seven-digit Article CID Number.

ISSN: 0277-786X
ISSN: 1996-756X (electronic)

ISBN: 9781510624689
ISBN: 9781510624696 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

SPIE.org

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